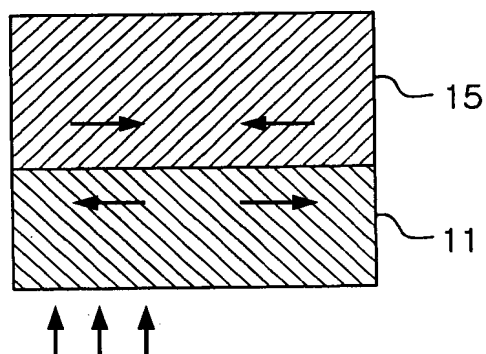


METHOD FOR MANUFACTURING GALLIUM NITRIDE(GaN) BASED SINGLE
CRYSTALLINE SUBSTRATE

Inventor: NA, Jeong Seok et al.

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PRIOR ART

FIG. 1

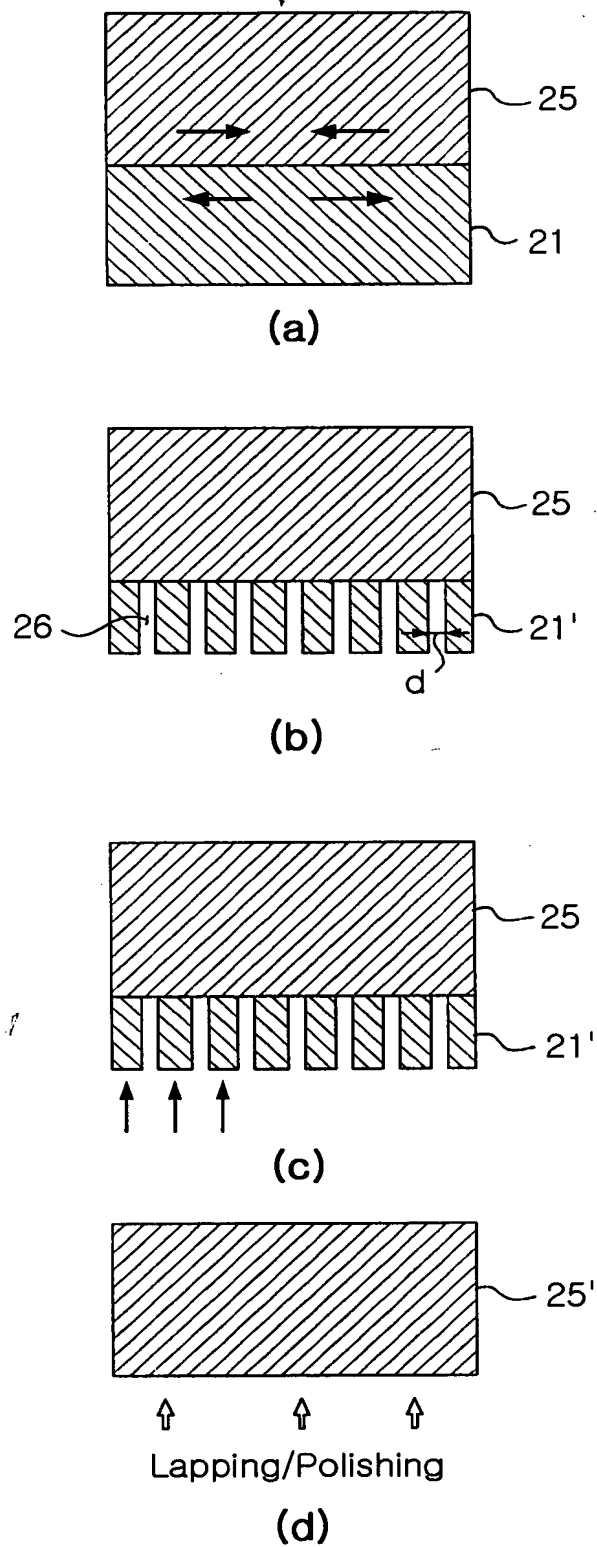


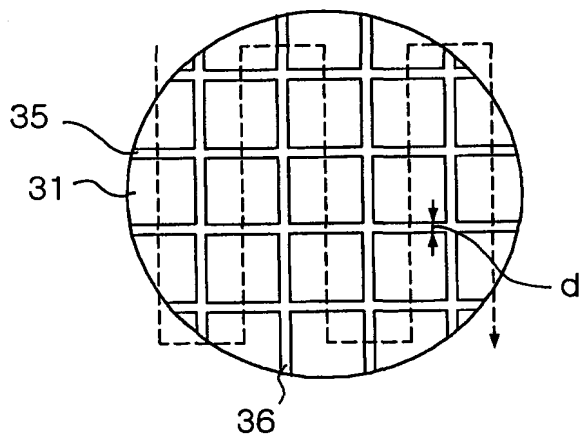
FIG. 2

METHOD FOR MANUFACTURING GALLIUM NITRIDE(GaN) BASED SINGLE
CRYSTALLINE SUBSTRATE

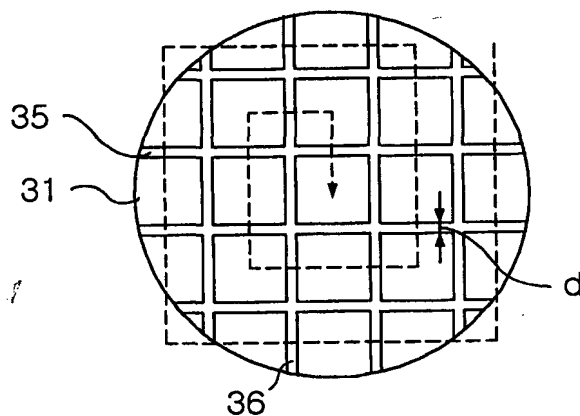
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(a)



(b)

FIG. 3